

## **650V N-Channel MOSFET**

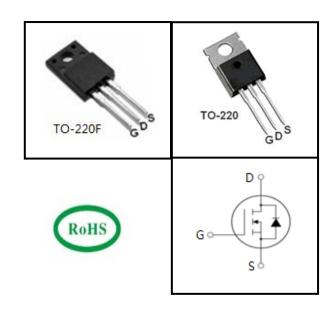
#### **FEATURES**

- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

#### **APPLICATIONS**

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)

Device Marking	and Package I	Information
Device	Package	Marking
TMA20N65H	TO-220F	A20N65H
TMP20N65H	TO-220	P20N65H



<b>Absolute Maximum Ratings</b> $T_C = 25^{\circ}C$ , unless otherwise noted					
Barranatar	Symbol	Value		11!1	
Parameter		TO-220F	TO-220	Unit	
Drain-Source Voltage (V <sub>GS</sub> = 0V)	V <sub>DSS</sub>	650		V	
Continuous Drain Current	I <sub>D</sub>	20		А	
Pulsed Drain Current (note1)	I <sub>DM</sub>	80		А	
Gate-Source Voltage	V <sub>GSS</sub>	±30		V	
Single Pulse Avalanche Energy (note2)	E <sub>AS</sub>	1350		mJ	
Avalanche Current (note1)	I <sub>AR</sub>	16		А	
Repetitive Avalanche Energy (note1)	E <sub>AR</sub>	90		mJ	
Power Dissipation (T <sub>C</sub> = 25°C)	P <sub>D</sub>	120	416	W	
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55~+150		°C	

Thermal Resistance				_	
Parameter	Value		lue	11!1	
Parameter	Symbol	TO-220F	TO-220	Unit	
Thermal Resistance, Junction-to-Case	R <sub>thJC</sub>	1.04	0.3	°C/W	
Thermal Resistance, Junction-to-Ambient	R <sub>thJA</sub>	62.5	60	30/00	



<b>Specifications</b> $T_J = 25^{\circ}C$ , unless otherwise noted								
Davamatar		T O W.	Value					
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static								
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0V, I_{D} = 250\mu A$	650			V		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 650V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1	μA		
Gate-Source Leakage	I <sub>GSS</sub>	$V_{GS} = \pm 30V$			±100	nA		
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3.0		4.0	V		
Drain-Source On-Resistance (Note3)	R <sub>DS(on)</sub>	$V_{GS} = 10V, I_{D} = 10A$		0.35	0.45	Ω		
Dynamic								
Input Capacitance	C <sub>iss</sub>	V 0V		2978				
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0V,$ $V_{DS} = 25V,$		291		pF		
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1.0MHz		40				
Total Gate Charge	$Q_g$			80		nC		
Gate-Source Charge	$Q_{gs}$	$V_{DD} = 520V, I_{D} = 20A,$ $V_{GS} = 10V$		12				
Gate-Drain Charge	$Q_{gd}$	63		34				
Turn-on Delay Time	t <sub>d(on)</sub>			37				
Turn-on Rise Time	t <sub>r</sub>	$V_{DD} = 325V, I_{D} = 20A,$		66				
Turn-off Delay Time	t <sub>d(off)</sub>	$R_G = 25 \Omega$		175		ns		
Turn-off Fall Time	t <sub>f</sub>			84				
Drain-Source Body Diode Characteristics								
Continuous Body Diode Current	I <sub>S</sub>	T 05.00			20	Δ.		
Pulsed Diode Forward Current	I <sub>SM</sub>	T <sub>C</sub> = 25 °C			80	А		
Body Diode Voltage	V <sub>SD</sub>	$T_J = 25^{\circ}C$ , $I_{SD} = 20A$ , $V_{GS} = 0V$			1.4	V		
Reverse Recovery Time	t <sub>rr</sub>	$V_{GS} = 0V, I_{S} = 20A,$		450		ns		
Reverse Recovery Charge	Q <sub>rr</sub>	di <sub>F</sub> /dt =100A /µs		7.1		μC		

#### Notes

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature
- 2.  $I_{AS}$  = 16A,  $V_{DD}$  = 50V,  $R_{G}$  = 25  $\Omega$ , Starting  $T_{J}$  = 25  $^{o}C$
- 3. Pulse Test: Pulse width ≤ 350µs, Duty Cycle ≤ 1%



### **Typical Characteristics** $T_J = 25^{\circ}C$ , unless otherwise noted

Figure 1. Output Characteristics (T<sub>J</sub> = 25°C)

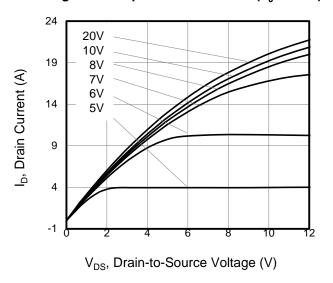


Figure 3. Drain Current vs. Temperature

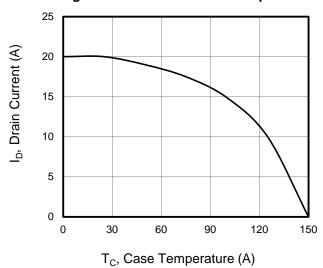


Figure 5. Transfer Characteristics

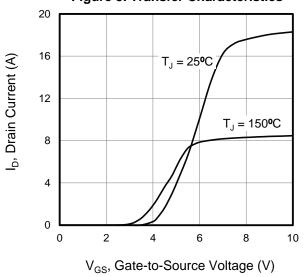


Figure 2. Body Diode Forward Voltage

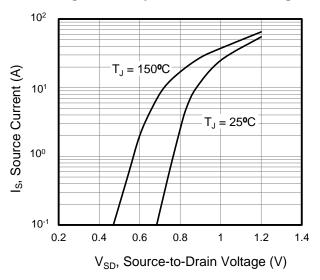


Figure 4. BV<sub>DSS</sub> Variation vs. Temperature

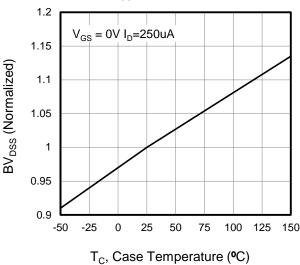
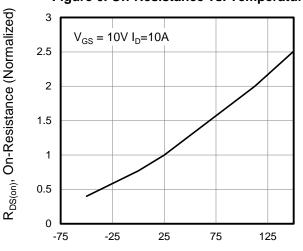


Figure 6. On-Resistance vs. Temperature



T<sub>J</sub>, Junction Temperature (°C)



## **Typical Characteristics** $T_J = 25^{\circ}\text{C}$ , unless otherwise noted

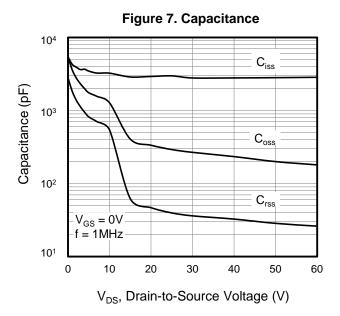
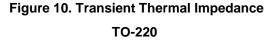
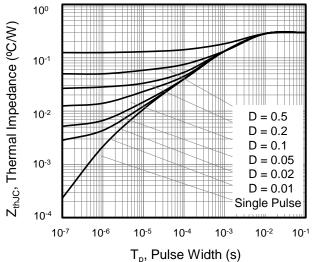


Figure 8. Gate Charge 12 V<sub>GS</sub>, Gate-to-Source Voltage (V)  $V_{DD} = 130V$ 10  $V_{DD} = 325V$ 8  $V_{DD} = 520V$ 6 2 0 0 20 40 60 100 Q<sub>q</sub>, Total Gate Charge (nC)

Figure 9. Transient Thermal Impedance
TO-220F

Z<sub>th,JC</sub>, Thermal Impedance (°C/W)





10<sup>1</sup>  $Z_{\text{thJC}}$ , Thermal Impedance (°C/W) 100 10-1 D = 0.5D = 0.2D = 0.1D = 0.0510-2 D = 0.02D = 0.01Single Pulse 10-3 10-6 10-5 10-3 10-4 10-2 100 10-1 T<sub>p</sub>, Pulse Width (s)

V3.0 4 www.tsinghuaicwx.com



Figure A: Gate Charge Test Circuit and Waveform

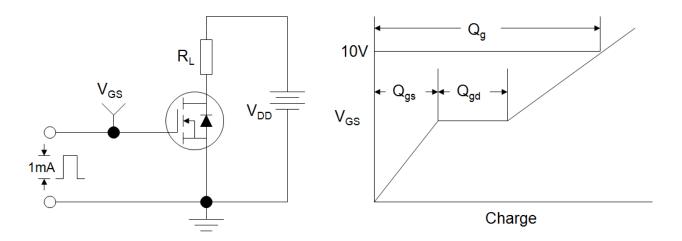


Figure B: Resistive Switching Test Circuit and Waveform

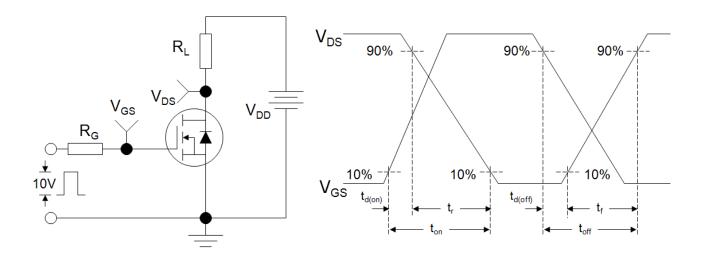
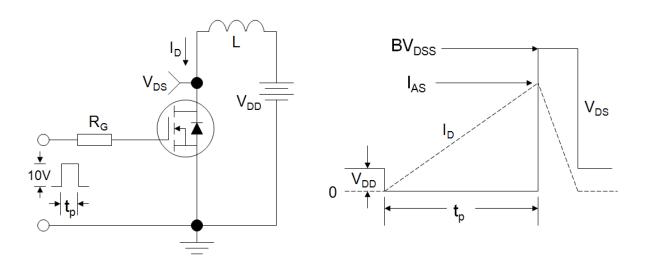
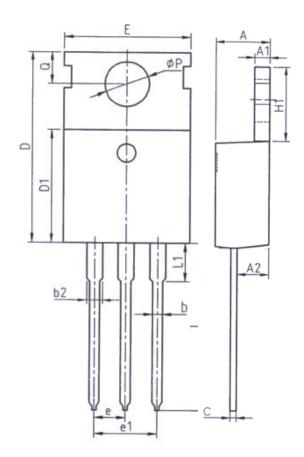


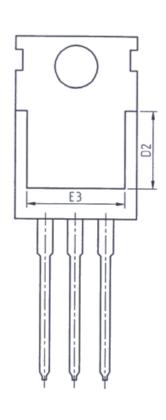
Figure C: Unclamped Inductive Switching Test Circuit and Waveform



V3.0 5 www.tsinghuaicwx.com

# **TO-220**



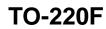


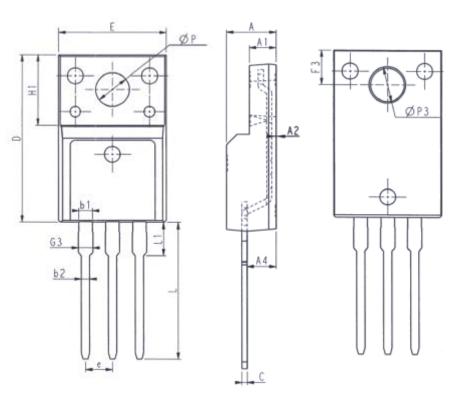
Unit: mm					
Symbol	Min.	Max.			
Α	4. 37	4. 77			
A1	1. 25	1. 45			
A2	2. 20	2. 60			
b	0. 70	0. 95			
b2	1. 17	1. 47			
С	0. 40	0. 65			
D	15. 10	16. 10			
D1	8. 80	9. 40			
D2	5. 50	_			

Unit: mm					
Symbol	Min.	Max.			
E	9. 70	10. 30			
E3	7. 00	-			
е	2. 54BSC				
e1	5. 08BSC				
H1	6. 25	6. 85			
L	12. 75	13.80			
L1	-	3. 40			
P	3. 40	3. 80			
Q	2. 60	3. 00			









Unit: mm			Unit: mm			
Symbol Min.		Max.	Symbol	Min.	Max.	
E	9.96	10.36	L	12. 68	13. 28	
Α	4. 50	4. 90	L1	2. 93	3. 13	
<b>A</b> 1	2. 34	2. 74	Р	3. 03	3. 38	
A2	0. 30	0. 60	Р3	3. 15	3. 65	
A4	2. 56	2. 96	F3	3. 15	3. 45	
С	0.40	0. 65	G3	1. 25	1. 55	
D	15. 57	16. 17	b1	1. 18	1. 43	
H1	6. 70REF		b2	0. 70	0. 95	
е	2. 54BSC					

V3.0 7 www.tsinghuaicwx.com



#### Disclaimer

All product specifications and data are subject to change without notice.

For documents and material available from this datasheet, Wuxi Unigroup does not warrant or assume any legal liability or responsibility for the accuracy, completeness of any product or technology disclosed hereunder.

No license, express or implied, by estoppels or otherwise, to any intellectual property rights is granted by this document or by any conduct of Wuxi Unigroup.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling Wuxi Unigroup products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Wuxi Unigroup for any damages arising or resulting from such use or sale.

Wuxi Unigroup disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Wuxi Unigroup's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

Wuxi Unigroup Microelectronics CO., LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.

In the event that any or all Wuxi Unigroup products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.

Information (including circuit diagrams and circuit parameters) herein is for example only. It is not guaranteed for volume production. Wuxi Unigroup believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

V3.0 8 www.tsinghuaicwx.com

## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by UNIGROUP manufacturer:

Other Similar products are found below:

614233C 648584F MCH3443-TL-E MCH6422-TL-E FDPF9N50NZ FW216A-TL-2W FW231A-TL-E APT5010JVR NTNS3A92PZT5G IRF100S201 JANTX2N5237 2SK2464-TL-E 2SK3818-DL-E FCA20N60\_F109 FDZ595PZ STD6600NT4G FSS804-TL-E 2SJ277-DL-E 2SK1691-DL-E 2SK2545(Q,T) D2294UK 405094E 423220D MCH6646-TL-E TPCC8103,L1Q(CM 367-8430-0972-503 VN1206L 424134F 026935X 051075F SBVS138LT1G 614234A 715780A NTNS3166NZT5G 751625C 873612G IRF7380TRHR IPS70R2K0CEAKMA1 RJK60S3DPP-E0#T2 RJK60S5DPK-M0#T0 APT5010JVFR APT12031JFLL APT12040JVR DMN3404LQ-7 NTE6400 JANTX2N6796U JANTX2N6784U JANTXV2N5416U4 SQM110N05-06L-GE3 SIHF35N60E-GE3